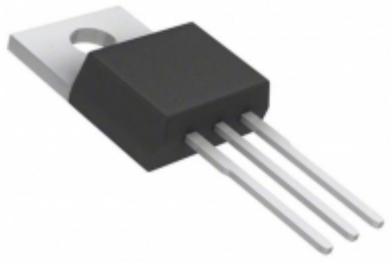


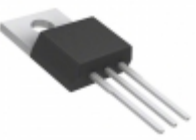
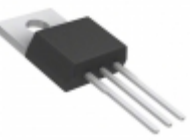



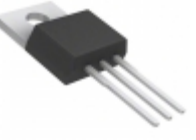
	<h2 style="color: red;">FQP33N10L</h2>
	<p>Hersteller-Teilenummer: FQP33N10L</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 100V 33A TO-220</p> <p>Datenblätter: 1.FQP33N10L.pdf 2.FQP33N10L.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 34502 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQP33N10L
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 100V 33A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	34502 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	127W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	33A (Tc)
Rds On (Max) @ Id, Vgs	52 mOhm @ 16.5A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	40nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	1630pF @ 25V
Verpackung	Tube

FQP33N10L ist neu im Original, Suche FQP33N10L Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP33N10L Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQP33N10L: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQP34N20L AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 31A TO-220</p>	 <p>FQP32N20C_F080 Fairchild/ON Semiconductor MOSFET N-CH 200V 28A TO-220</p>	 <p>FQP34N20L Fairchild/ON Semiconductor MOSFET N-CH 200V 31A TO-220</p>	 <p>FQP3N25 Fairchild/ON Semiconductor MOSFET N-CH 250V 2.8A TO-220</p>
 <p>FQP34N20 AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 31A TO-220</p>	 <p>FQP33N10L AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 33A TO-220</p>	 <p>FQP33N10 AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 33A TO-220</p>	 <p>FQP33N10 Fairchild/ON Semiconductor MOSFET N-CH 100V 33A TO-220</p>

heiße Teile

Mehr

⊗ FQP22P10	↔ FQP24N08	⇒ FQP24N08	D FQP24N40	↔ FQP27N25
⊣ FQP27N25	⊗ FQP27N60	D FQP27P06	⇒ FQP27P06	↔ FQP2N60B
⊗ FQP2N60C	⊣ FQP2N60C	⊗ FQP2N65C	↔ FQP30N06	↔ FQP30N06
D FQP30N06L	⊗ FQP30N06L	⊣ FQP32N12V2	⊗ FQP32N12V2	↔ FQP32N20
⇒ FQP32N20C	↔ FQP32N20C	⊗ FQP33N10	⊣ FQP33N10	↔ FQP33N10L
↔ FQP34N20	⇒ FQP34N20	D FQP34N20L	⊗ FQP34N20L	⊣ FQP3N50C
⊗ FQP3N60C	D FQP3N60C	⇒ FQP3N80C	↔ FQP3N80C	↔ FQP44N08
⊣ FQP44N08	⊗ FQP44N10	↔ FQP44N10	⇒ FQP44N10F	↔ FQP44N10F
⊗ FQP45N03L	⊣ FQP45N03LM	⊗ FQP45N15V2	D FQP45N15V2	↔ FQP45N20A
↔ FQP46N15	⊗ FQP46N15	⊣ FQP47N06	⊗ FQP47P06	↔ FQP47P06

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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